

S1D0150120B



TriQSiC™ 1200V Silicon Carbide Schottky Diode

Features

- 1.2kv schottky Rectifier
- Zero Reverse Recovery Current / Zero forward recovery
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Low forward voltage
- Positive Temperature Coefficient on V_F



Chip Outline

Type	Die size (W x L) mm	Anode	Cathode
S1D015120B	2.70 x 2.70	Al	Ag

Table 1 Key performance and package parameters

Type	V_{RRM}	$I_F(T_C = 135^{\circ}C)$	Q_C	$T_{J,max}$
S1D015120B	1200V	23A	81nC	175°C

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1、Maximum ratings

Table 2 Maximum rating ($T_c = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V	-	
V_{RSM}	Surge Peak Reverse Voltage	1300	V	-	
V_R	DC Peak Reverse Voltage	1200	V	-	
I_F	Continuous Forward Current	47 23 15	A	$T_c = 25^{\circ}\text{C}$ $T_c = 135^{\circ}\text{C}$ $T_c = 154^{\circ}\text{C}$	Note1
I_{FSM}	Non-Repetitive Peak Forward Surge Current	135	A	$T_c = 25^{\circ}\text{C}$, $t_p = 10\text{ms}$, Half Sine Pulse	
T_{stg}, T_J	Operating Junction Range	-55 to +175	$^{\circ}\text{C}$	-	

Note1. Assumes $R_{\theta JC}$ Thermal Resistance of 0.72°C/W or less

3、Electrical characteristics

Table 4 Electrical characteristics ($T_c = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.37 1.84	1.6 2.2	V	$I_F = 15\text{A}$, $T_J = 25^{\circ}\text{C}$ $I_F = 15\text{A}$, $T_J = 175^{\circ}\text{C}$	Fig.1
I_R	Reverse Current	1 10	100 200	μA	$V_R = 1200\text{V}$, $T_J = 25^{\circ}\text{C}$ $V_R = 1200\text{V}$, $T_J = 175^{\circ}\text{C}$	Fig.2
Q_c	Total Capacitive Charge	81	-	nC	$V_R = 800\text{V}$, $I_F = 15\text{A}$ $di/dt = 200\text{A}/\mu\text{s}$, $T_J = 25^{\circ}\text{C}$	Fig.4
C	Total Capacitance	1600 72 52	-	pF	$V_R = 0\text{V}$, $T_J = 25^{\circ}\text{C}$, $f = 1\text{MHz}$ $V_R = 400\text{V}$, $T_J = 25^{\circ}\text{C}$, $f = 1\text{MHz}$ $V_R = 800\text{V}$, $T_J = 25^{\circ}\text{C}$, $f = 1\text{MHz}$	Fig.3
E_C	Capacitance Stored Energy	44	-	μJ	$V_R = 800\text{V}$	Fig.5

4、Electrical characteristic diagrams

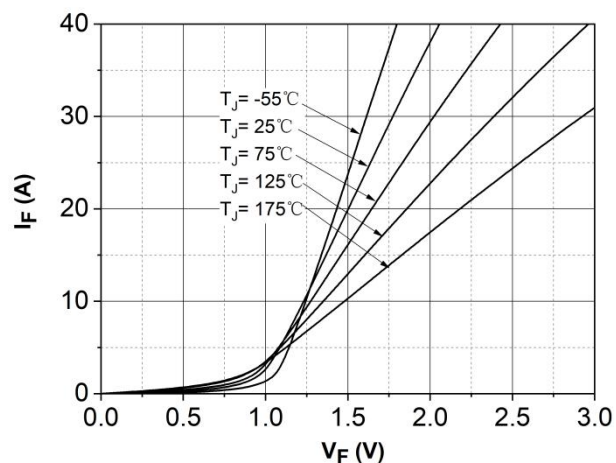


Figure 1. Forward Characteristics

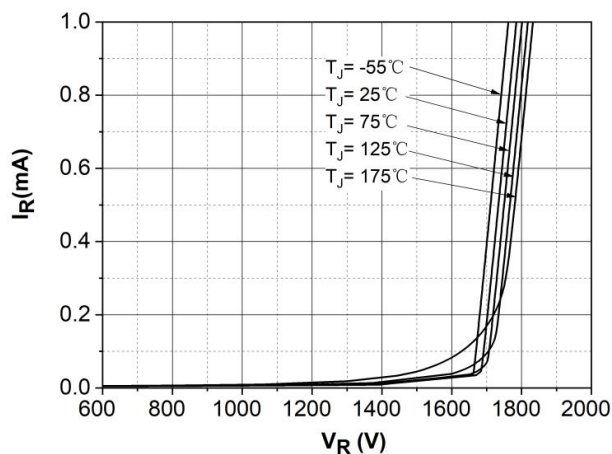


Figure 2. Reverse Characteristics

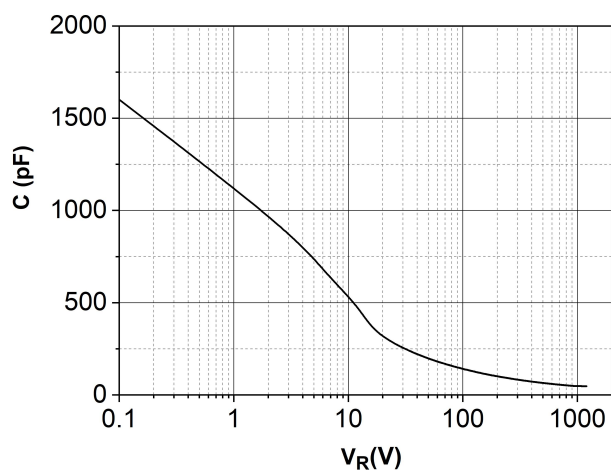


Figure 3. Capacitance vs. Reverse Voltage

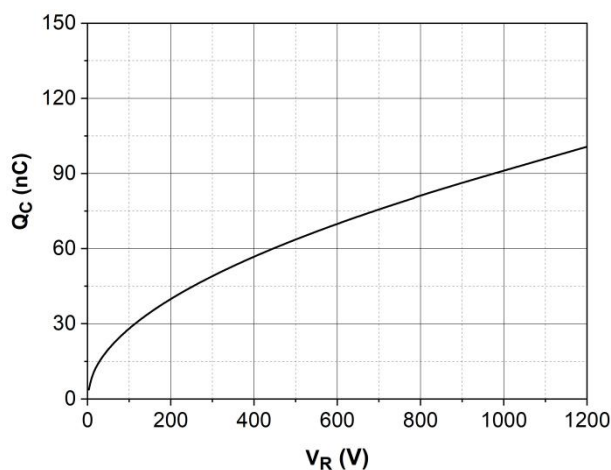


Figure 4. Recovery Charge vs. Reverse Voltage

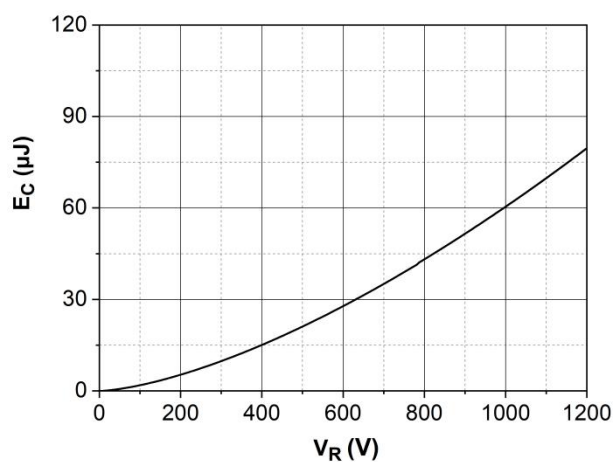
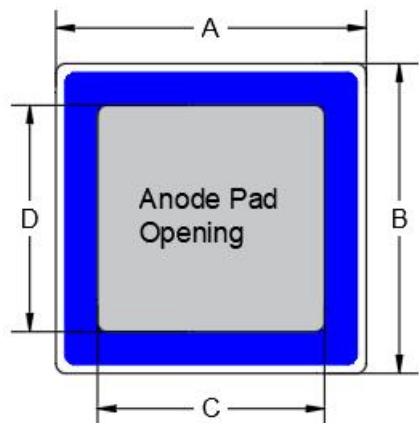


Figure 5. Typical Capacitance Stored Energy

5、Mechanical Parameters

Parameter	Typ.	Unit
Die Size	2.70*2.70	mm
Anode Pad Opening	1.80*1.80	mm
Thickness	175	μm
Anode Metallization (Al)	4	μm
Cathode Metallization (Ag)	1	μm

6、Chip Dimensions



Symbol	Dimension / mm
A	2.70
B	2.70
C	1.80
D	1.80

Revision history

Document version	Date of release	Description of changes
V02_00	2024-09-06	--
V02_01	2024-10-28	--

Attention

1. Rohs compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/ EC (RoHS2), as implemented January 2, 2013.

2. REACH compliance

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a Sichain representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

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